TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

T6L08

GATE DRIVER FOR TFT LCD PANELS

The T6L08 is a 240-channel-output gate driver for TFT LCD panels. In addition to high-voltage operation (liquid crystal drive voltage = Max 42 V), this device accepts external input of the panel drive voltage, allowing you to change the low-level output voltage. Thus, this device can be used for various TFT LCD panel drive systems. The T6L08 offers high integration circuit due to CMOS technology.

Unit: mm USER AREA PITCH T6L08 IN OUT Please contact Toshiba or a distributor for the latest TCP specification and product line-up. TCP (Tape Carrier Package)

FEATURES

LCD drive output pins : 240 pins

LCD drive voltage : Max V_{EE} + 42 V

Data transfer method : Bidirectional shift register

Operating temperature: -20 to 75°C

: Tape carrier package (TCP) Package

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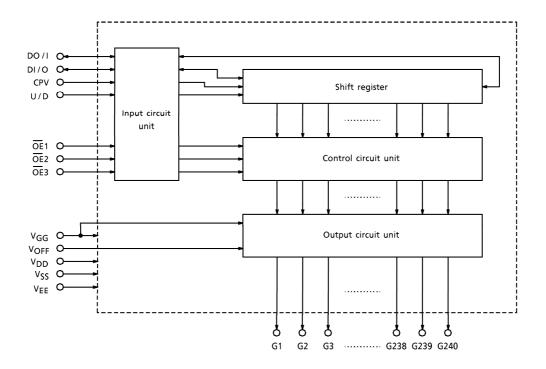
cause the device to malfunction. This is especially true for devices in which the surface (back), or side of the chip is exposed. When designing circuits, make sure that devices are protected against incident light from external sources. Exposure to light both during regular operation and during inspection must be taken into account.

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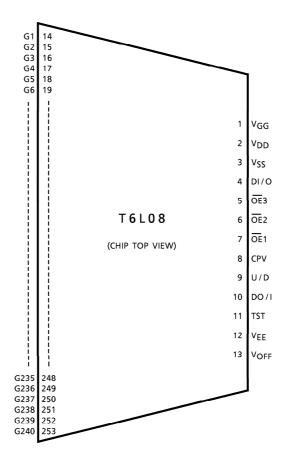
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BLOCK DIAGRAM



PIN ASSIGNMENT



The above diagram shows the device's pin configuration only and does not necessarily correspond to the pad layout on the chip. Please contact Toshiba or our distributors for the latest TCP specification.

PIN FUNCTION

PIN NAME	1/0			FUNCTION				
		Vertical shift data I/O pins These pins are used to input and output shift data. These pins are switched between input and output by setting the U/D pin as shown below.						
			U/D	DI/O	DO/I			
			Н	Input	Output			
DI/O	1/0		L	Output	Input			
DO/I	1/0	This pin is of the LCD rising edge When set for When two	When set for input This pin is used to feed data into the shift registers at the first stage of the LCD driver. The data is latched into the shift registers at the rising edge of CPV. When set for output When two or more T6L08s are cascaded, this pin outputs the data to be fed into the next stage. This data changes state synchronously					
U/D	Input	Transfer direct This pin spe the shift re When U G1→G2 When U G240→0 The voltage	Transfer direction select pin This pin specifies the direction in which data is transferred through the shift registers. When U/D is high, data is shifted in the direction G1 → G2 → G3 → G4 → G5 → ··· → G240 When U/D is low, the direction is reversed to give G240 → G239 → G238 → G237 → ··· → G1 The voltage applied to this pin must be a DC-level voltage that is either high (VDD) or low (VSS).					
CPV	Input		This is the shift clock for the shift registers. Data is shifted through the shift registers synchronously with the rising edge of CPV.					
OE1 to 3	Input	Output enable These signa (G1 to G24) The VOR	Output enable input These signals control the data appearing at the LCD panel drive pins (G1 to G240). The VOFF voltage is output when OE1 to 3 are high; normal shift data is output when OE1 to 3 are low.					
VOFF	Input	Analog input pin If the shift register data is low (= logic 0), the voltage on this pin is forwarded to the output pin corresponding to the shift register. If OE1 to 3 are high, the voltage on this pin is output irrespective of whether the shift register data is high or low.						
TST	Input		Test pin Leave this pin open.					
G1 to 240	Output	LCD panel driv These pins V _{GG} or V _O	ve pins output the sh _{FF} , depending	ift register da on the contr		tage applied to 1 to 3.		
V _{GG}	_	Power supply						
V _{DD}		Power supply for the internal logic						
V _{SS}	<u> </u>	Power supply for the internal logic Power supply for LCD drive and the internal logic						
V _{EE}		Tower supply for LCD unive and the internal logic						

DEVICE OPERATION (see timing diagram)

(1) Shift data transfer method

The input shift data is latched into the internal register synchronously with the rising edge of the shift clock CPV. When the data is shifted to the next register at the next rising edge of CPV, new input shift data is simultaneously latched into.

In the case of shift data output, the data in the last shift register is output synchronously with the falling edge of CPV (the output high voltage level is V_{DD}; the output low voltage level is V_{SS}).

U/D	DI/O	DO/I	DATA TRANSFER METHOD
Н	Input	Output	$DI/O \rightarrow G1 \rightarrow G2 \rightarrow G3 \rightarrow \cdots \rightarrow G240 \rightarrow DO/I$
L	Output	Input	$DO/I \rightarrow G240 \rightarrow G239 \rightarrow G238 \rightarrow \cdots \rightarrow G1 \rightarrow DI/O$

(2) LCD panel drive outputs

If the shift register data corresponding to an output pin is high (= logic 1), the pin outputs V_{GG} ; if the shift register data is low (= logic 0), the pin outputs V_{OFF} .

However, if $\overline{OE}1$ to 3 corresponding to the output pins are high, the pins output V_{OFF} irrespective of whether the shift register data is high or low. The LCD panel drive outputs are controlled by \overline{OE} as shown below.

OUTPUT ENABLE PIN		LCD PANEL DRIVE OUTPUTS		
H/L OE1 to 3		LCD PANEL DRIVE PINS CONTROLLED BY OF	OUTPUT	
	ŌĒ1	G1, G4, G7, G10 ······ G235, G238	Name al data	
L	OE2	G2, G5, G8, G11 ······ G236, G239	Normal data output	
	OE3	G3, G6, G9, G12 ······ G237, G240		
	OE1	G1, G4, G7, G10 ······ G235, G238		
Н	OE2	G2, G5, G8, G11 ······ G236, G239	V _{OFF}	
	OE3	G3, G6, G9, G12 ······ G237, G240		

(3) Voltage setting

(Example 1) Negative voltage output

Logic input : High = 5 V or low = 0 V amplitude

Supply voltage : $V_{GG} = 20 V$

 $V_{DD} = 5 V$ $V_{OFF} = -5 V$ $V_{EE} = -10 V$

LCD panel drive output : High level = V_{GG} (20 V)

Low level = V_{OFF} (-5 V)

(Example 2) Positive voltage output

Logic input : High = 5 V or low = 0 V amplitude

Supply voltage : $V_{GG} = 30 V$

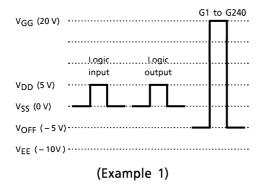
 $V_{DD} = 5 V$

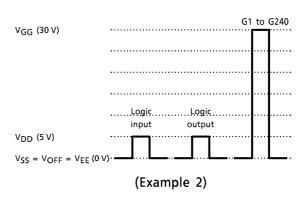
 $V_{OFF} = V_{SS} = V_{EE} = 0 V$

LCD panel drive output : High level = V_{GG} (30 V)

Low level = V_{OFF} (0 V)

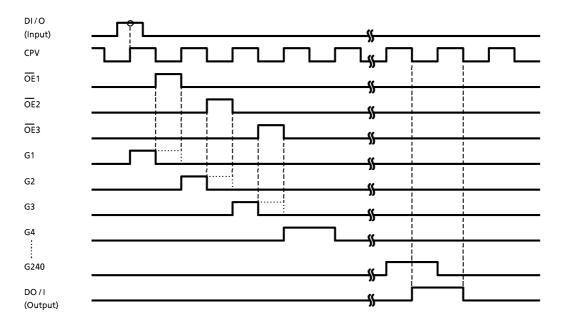
(*) Logic input pins : DI/O or DO/I, CPV, $\overline{OE}1$ to 3, U/D



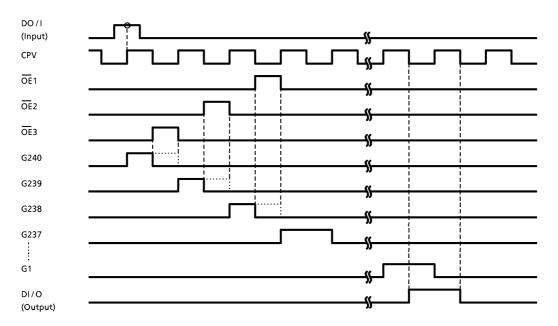


TIMING DIAGRAMS

• UP mode (U/D = high)



• DOWN mode (U/D = low)



ABSOLUTE MAXIMUM RATINGS $(V_{SS} = 0 V)$

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage (1)	V _{GG} – V _{EE}	15.0 to 45.0	V
Supply Voltage (2)	V _{DD}	-0.3 to 7.0	V
Supply Voltage (3)	V _{EE}	- 16.0 to 0.3	V
Input Voltage	V _{IN}	-0.3 to V _{DD} + 0.3	V
Analog Input Voltage	V _{OFF}	$V_{EE} - 0.3$ to $V_{GG} + 0.3$	V
Storage Temperature	TSTG	- 55 to 125	°C

RECOMMENDED OPERATING CONDITIONS ($V_{SS} = 0 V$)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage (1)	V _{GG} - V _{EE}	15.0 to 42.0	V
Supply Voltage (2)	V_{DD}	4.5 to 5.5	V
Supply Voltage (3)	V _{EE}	– 15.0 to 0	٧
Operating Temperature	T _{OP}	– 20 to 75	°C
Operating Frequency	fCPV	DC to 100	kHz
Output Load Capacitance	CL	300 (max)	pF/pin
Analog Input Voltage	V _{OFF} (Note 1)	– 15.0 to 0	V

(Note 1) : $V_{EE} \le V_{OFF}$

ELECTRICAL CHARACTERISTICS

DC CHARACTERISTICS (Referenced to $V_{GG} - V_{EE} = 42 \text{ V}$ at $T_{a} = -20 \text{ to } 75^{\circ}\text{C}$ unless otherwise noted)

PARA	METER	SYMBOL	TEST CIR- CUIT	TEST CONDITIONS	MIN	TYP.	MAX	UNIT	RELEVANT PIN
Input	Low Level	VIL			V _{SS}	_	0.2 × (V _{DD} - V _{SS}) + V _{SS}	v	(Note 2)
Voltage	High Level	V _{IH}			0.8 × (V _{DD} - V _{SS}) + V _{SS}		V _{DD}	V	(Note 2)
Output Voltage	Low Level High Level	V _{OL}		$I_{OL} = 40 \mu\text{A}$ $I_{OH} = -40 \mu\text{A}$	V _{SS} V _{DD} – 0.3 V		V _{SS} + 0.3 V	V	DI/O, DO/I
Output	Low Level High Level	ROL	_	$V_{OUT} = V_{OFF} + 0.5 V$ $V_{OUT} = V_{GG} - 0.5 V$		_	1500 1500	Ω	G1 to G240
Input Leal Current	kage	IN	ı		- 1.0	_	1.0	μΑ	(Note 2)
Current Consumpt	ion (1)	lgg	1	f _{CPV} = 100 kHz	_		200	μΑ	V _{GG}
Current Consumpt	ion (2)	lDD			_	_	900	μΑ	v _{DD}
Current Consumpt	ion (3)	ISS			- 200	_	200	μΑ	V _{SS}

(Note 2) : Input pins include···DI/O, DO/I, U/D, CPV, $\overline{\text{OE}}1$ to 3

AC CHARACTERISTICS (Referenced to $V_{GG} - V_{EE} = 42 \text{ V}$ at Ta = $-20 \text{ to } 75^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CIR- CUIT	TEST CONDITIONS	MIN	TYP.	MAX	UNIT
Clock Period	tCPV		_	10	_	_	μs
CPV Pulse Width (H)	tCPVH	_	_	4	_	_	μs
CPV Pulse Width (L)	tCPVL		_	4	_	_	μs
OE Enable Time	twOE		_	1	_	_	μs
Data Set-up Time	tsDI	_	_	1	_	_	μs
Data Hold Time	thDI	_	_	1	_	_	μs
Output Delay Time (1)	tpdDO	_	$C_L = 50 pF$	_	_	1	μs
Output Delay Time (2)	tpdG	_	C _L = 300 pF	_	_	1	μs
Output Delay Time (3)	tpdOE	_	C _L = 300 pF	_	_	1	μs

